

International **IR** Rectifier

PD-2.060 rev. C 11/97

50SQ... SERIES

SCHOTTKY RECTIFIER

5 Amp

Major Ratings and Characteristics

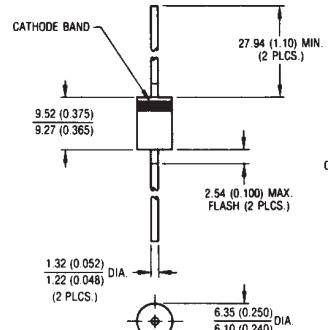
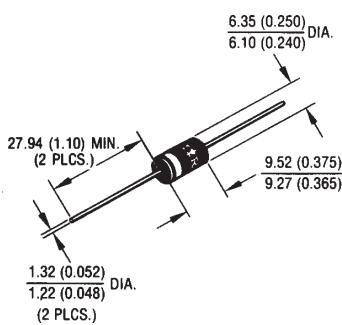
Characteristics	50SQ...	Units
$I_{F(AV)}$ Rectangular waveform	5	A
V_{RRM} range	80 to 100	V
I_{FSM} @ $t_p = 5\ \mu s$ sine	1900	A
V_F @ 5Apk, $T_J = 125^\circ C$	0.52	V
T_J range	-55 to 175	°C

Description/Features

The 50SQ... axial leaded Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to $175^\circ C$ junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- $175^\circ C T_J$ operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability

CASE STYLE AND DIMENSIONS



Conforms to JEDEC Outline DO - 204AR

Dimensions in millimeters and inches

Voltage Ratings

Part number	50SQ080	50SQ100
V_R Max. DC Reverse Voltage (V)		
V_{RWM} Max. Working PeakReverse Voltage (V)	80	100

Absolute Maximum Ratings

Parameters	50SQ	Units	Conditions		
$I_{F(AV)}$ Max.AverageForwardCurrent * See Fig. 5	5	A	50% duty cycle @ $T_C = 119^\circ\text{C}$, rectangular waveform		
I_{FSM} Max.PeakOneCycleNon-Repetitive Surge Current *See Fig. 7	1900	A	5μs Sine or 3μs Rect. pulse	Following any rated load condition and with rated V_{RWM} applied	
	290		10ms Sine or 6ms Rect. pulse		
E_{AS} Non-Repetitive Avalanche Energy	15	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 1.0$ Amps, $L = 30$ mH		
I_{AR} Repetitive Avalanche Current	1.0	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical		

Electrical Specifications

Parameters	50SQ	Units	Conditions		
V_{FM} Max. Forward Voltage Drop (1) * See Fig. 1	0.66	V	@ 5A	$T_J = 25^\circ\text{C}$	
	0.77	V	@ 10A		
	0.52	V	@ 5A	$T_J = 125^\circ\text{C}$	
	0.62	V	@ 10A		
I_{RM} Max. Reverse Leakage Current (1) * See Fig. 2	0.55	mA	$T_J = 25^\circ\text{C}$	$V_R = \text{rated } V_R$	
	7	mA	$T_J = 125^\circ\text{C}$		
C_J Max. Junction Capacitance	500	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) 25°C		
L_S Typical Series Inductance	10	nH	Measured lead to lead 5mm from body		
dv/dt Max. Voltage Rate of Change (Rated V_R)	10,000	V/ μs			

(1) Pulse Width < 300μs, Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	50SQ	Units	Conditions	
T_J Max.JunctionTemperatureRange	-55to175	°C		
T_{sig} Max.Storage Temperature Range	-55to175	°C		
R_{thJL} Max.ThermalResistance Junction to Lead	8.0	°C/W	DCopera	* See Fig. 4 1/8inchleadlength
R_{thJA} Typical Thermal Resistance,44 Junction to Air		°C/W		
wt ApproximateWeight	1.4(0.049)	g(oz.)		
Case Style	DO - 204AR		JEDEC	

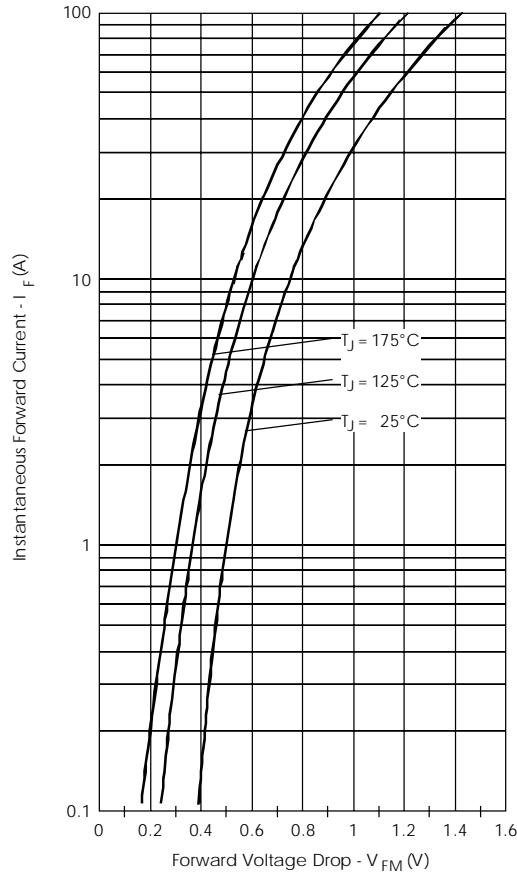


Fig.1-Maximum Forward Voltage Drop Characteristics

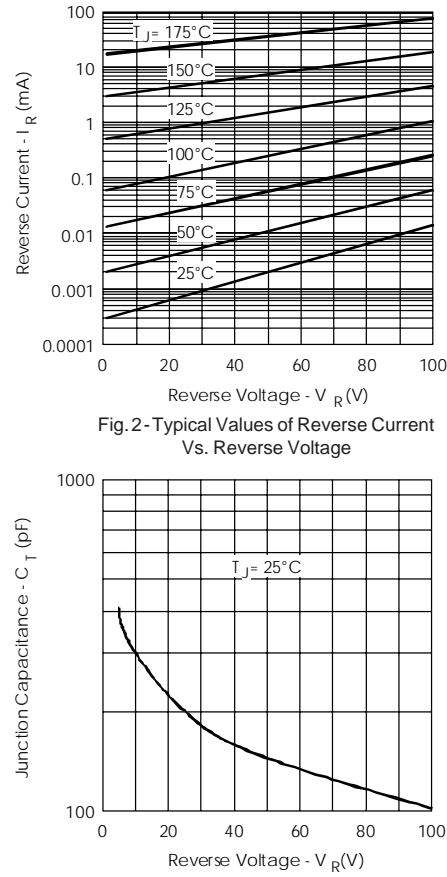


Fig.2-Typical Values of Reverse Current Vs. Reverse Voltage

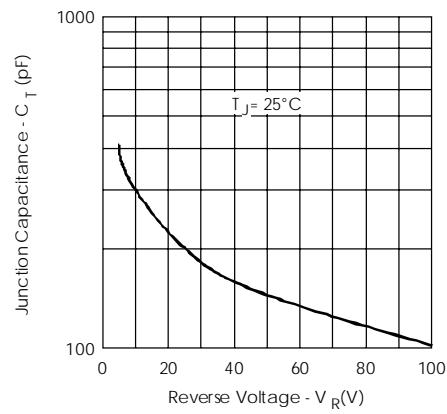


Fig.3-Typical Junction Capacitance Vs. Reverse Voltage

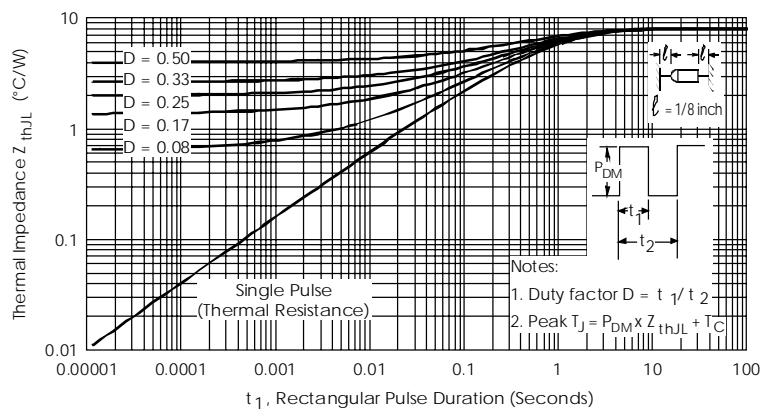


Fig.4-Maximum Thermal Impedance Z_{thJL} Characteristics

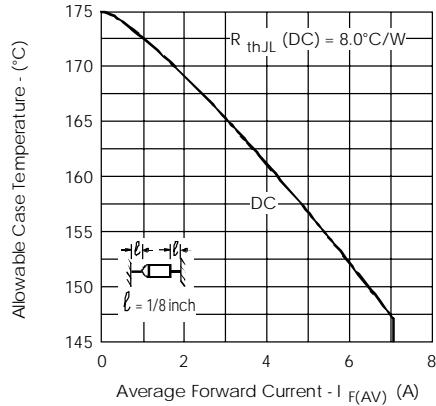


Fig.5-Maximum Allowable Case Temperature Vs. Average Forward Current

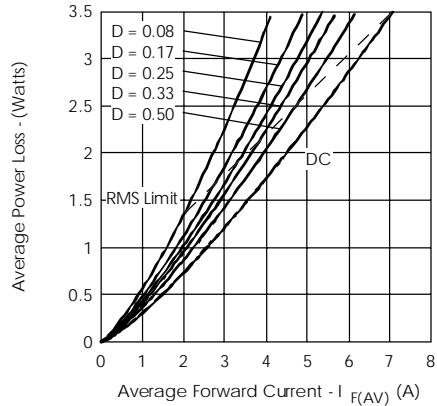


Fig.6-Forward Power Loss Characteristics

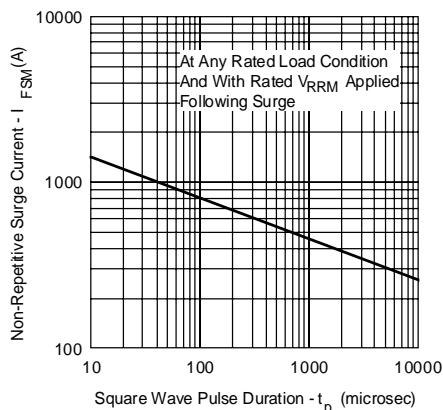


Fig.7-Maximum Non-Repetitive Surge Current

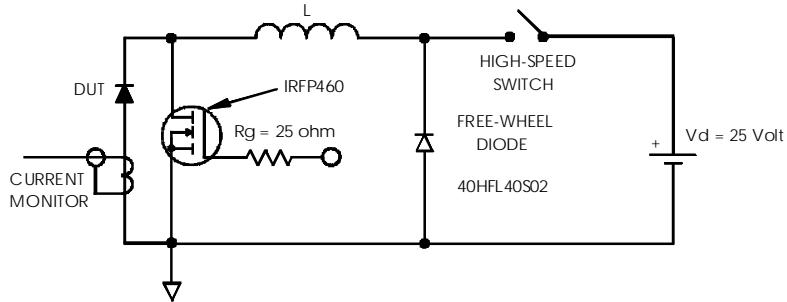


Fig.8-Unclamped Inductive Test Circuit